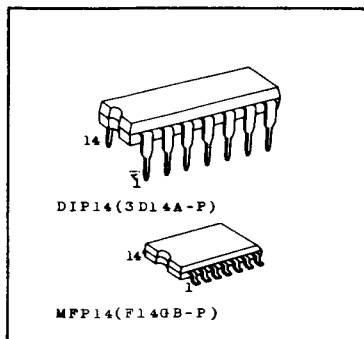
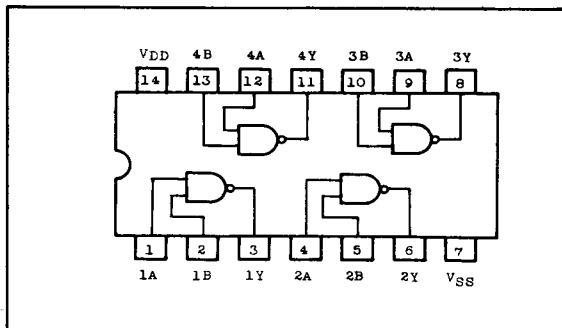


查询TC40H000F供应商

CMOS DIGITAL INTEGRATED CIRCUIT
SILICON MONOLITHIC**TC40H000P/F**

TC40H000 QUAD 2-INPUT NAND GATE

PIN CONNECTION



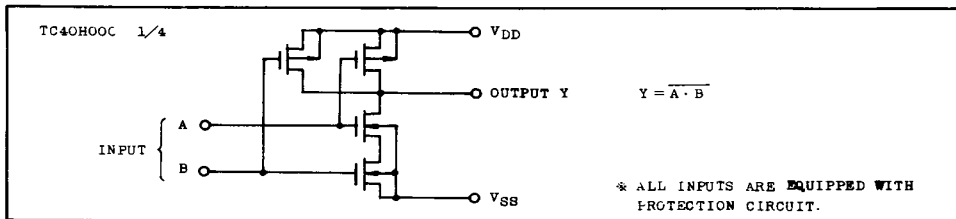
MAXIMUM RATINGS

| CHARACTERISTIC | SYMBOL | RATING | UNIT |
|---------------------|-----------|--|--------------------|
| Supply Voltage | V_{DD} | $V_{SS}-0.5 \sim V_{SS}+10$ | V |
| Input Voltage | V_{IN} | $V_{SS}-0.5 \sim V_{DD}+0.5$ | V |
| Output Voltage | V_{OUT} | $V_{SS}-0.5 \sim V_{DD}+0.5$ | V |
| Input Current | I_{IN} | ± 10 | mA |
| Power Dissipation | P_D | 300 (DIP) / 180 (MFP) | mW |
| Storage Temperature | T_{stg} | $-65 \sim 150$ | $^{\circ}\text{C}$ |
| Lead Temp./Time | T_{sol} | $260^{\circ}\text{C} \cdot 10 \text{ sec}$ | |

TRUTH TABLE

| INPUT | | OUTPUT |
|-------|---|--------|
| A | B | Y |
| L | L | H |
| H | L | H |
| L | H | H |
| H | H | L |

CIRCUIT DIAGRAM

RECOMMENDED OPERATING CONDITIONS ($V_{SS}=0V$)

| CHARACTERISTIC | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNIT |
|-----------------------|-----------|----------------|------|------|----------|--------------------|
| Supply Voltage | V_{DD} | - | 2.0 | - | 8.0 | V |
| Input Voltage | V_{IN} | - | 0 | - | V_{DD} | V |
| Operating Temperature | T_{opr} | - | -40 | - | 85 | $^{\circ}\text{C}$ |

TC40H000P/F

ELECTRICAL CHARACTERISTICS ($V_{SS}=0.0V$)

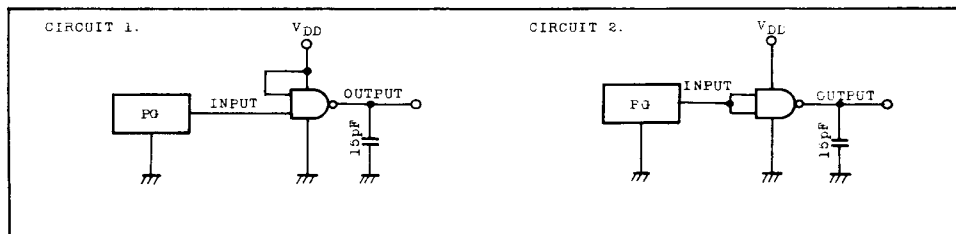
| CHARACTERISTIC | SYMBOL | TEST CONDITION | V_{DD} (V) | -40°C | | 25°C | | | 85°C | | UNIT |
|---------------------------|-----------------------|---|-----------------|-------|------|-------|------------|------|-------|------|---------|
| | | | | MIN. | MAX. | MIN. | TYP. | MAX. | MIN. | MAX. | |
| High Level Output Voltage | V_{OH} | $ I_{OUT} < 1\mu A$ $V_{IN}=V_{SS}, V_{DD}$ | 5 | 4.95 | - | 4.95 | 5.0 | - | 4.95 | - | V |
| Low Level Output Voltage | V_{OL} | $ I_{OUT} < 1\mu A$ $V_{IN}=V_{DD}$ | 5 | - | 0.05 | - | 0.0 | 0.05 | - | 0.05 | |
| High Level Output Current | I_{OH} | $V_{OH}=4.6V$ $V_{IN}=V_{SS}, V_{DD}$ | 5 | -0.52 | - | -0.44 | - | - | -0.36 | - | mA |
| Low Level Output Current | I_{OL} | $V_{OL}=0.4V$ $V_{IN}=V_{DD}$ | 5 | 1.4 | - | 1.1 | - | - | 0.8 | - | |
| Input Voltage | "H" Level V_{IH} | $ I_{OUT} < 1\mu A$ $V_{OUT}=0.5V$ | 5 | 4.0 | - | 4.0 | - | - | 4.0 | - | V |
| | "L" Level V_{IL} | $V_{OUT}=4.5V$ | 5 | - | 1.0 | - | - | 1.0 | - | 1.0 | |
| Input Current | "H" Level I_{IH} | $V_{IH}=8.0V$ | 8 | - | 0.3 | - | 10^{-5} | 0.3 | - | 1.0 | μA |
| | "L" Level I_{IL} | $V_{IL}=0.0V$ | 8 | - | -0.3 | - | -10^{-5} | -0.3 | - | -1.0 | |
| Quiescent Supply Current | I_{DD} | $*V_{IN}=V_{SS}, V_{DD}$ | 5 | - | 2.0 | - | 10^{-3} | 2.0 | - | 10.0 | μA |

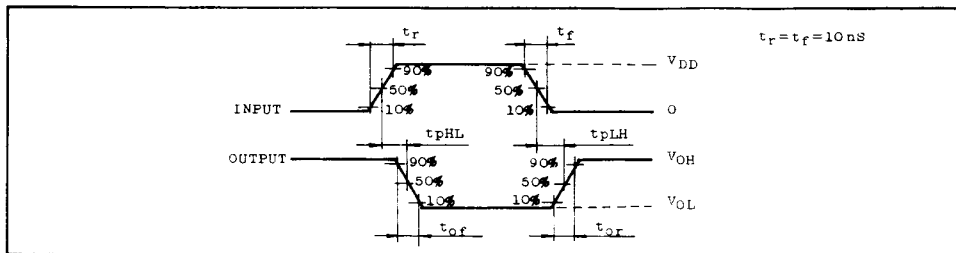
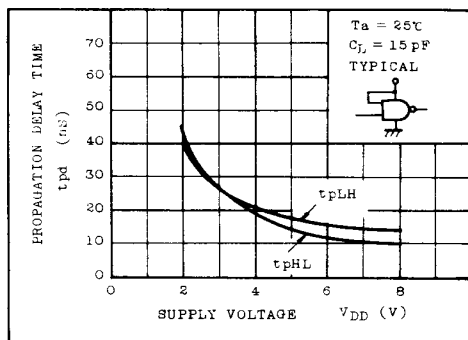
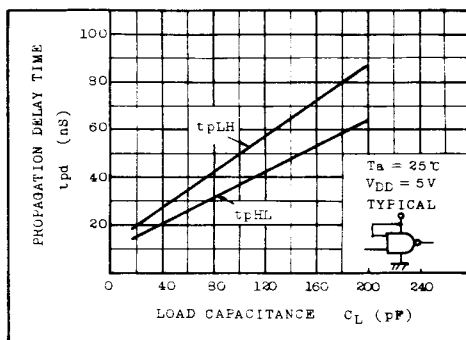
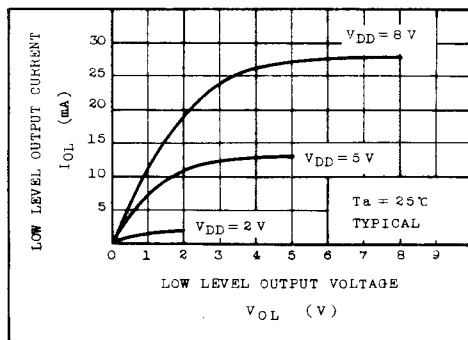
* All valid input combinations.

SWITCHING CHARACTERISTICS ($T_a=25^\circ C, V_{SS}=0.0V, C_L=15pF$)

| CHARACTERISTIC | | SYMBOL | TEST CONDITION | $V_{DD}(V)$ | MIN. | TYP. | MAX. | UNIT |
|------------------------|------------|-----------|----------------|-------------|------|------|------|------|
| Output Rise Time | | t_{or} | Circuit 1 | 5 | - | 26 | 40 | ns |
| Output Fall Time | | t_{of} | Circuit 1 | 5 | - | 16 | 30 | |
| Propagation Delay Time | (Low-High) | t_{pLH} | Circuit 1 | 5 | - | 18 | 27 | ns |
| | (High-Low) | t_{pHL} | | 5 | - | 14 | 21 | |
| Propagation Delay Time | (Low-High) | t_{pLH} | Circuit 2 | 5 | - | 13 | 20 | ns |
| | (High-Low) | t_{pHL} | | 5 | - | 15 | 23 | |
| Input Capacitance | | C_{IN} | | | - | 5 | - | pF |

SWITCHING TIME TEST CIRCUIT



TC40H000P/F**SWITCHING TIME TEST WAVEFORM** $t_{pd} - V_{DD}$  $t_{pd} - C_L$  $I_{OL} - V_{OL}$  $I_{OH} - (V_{DD} - V_{OH})$ 